



IFN

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Kazumasa TANIDA et al.

Docket No.: AI 317D1

Application No.: ~~11/306,707~~ 10/523,005

Confirmation No.: 4655

Filed: April 4, 2006

Art Unit: 2814

For: SEMICONDUCTOR DEVICE PRODUCTION
METHOD AND SEMICONDUCTOR DEVICE

Examiner: Hoa B. Trinh

INFORMATION DISCLOSURE STATEMENT (IDS)

MS Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir

Pursuant to 37 CFR 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the reference listed on the attached PTO/SB/08. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This is an information disclosure statement submitted in compliance with the timing requirements of 37 C.F.R. §1.114 after a Request for Continued Examination, but before a Notice of Allowance.

It is hereby certified that each item of information contained in the Information Disclosure Statement was first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this Information Disclosure Statement. Consideration of the listed document is respectfully requested.

Should any fee be required, however, the Commissioner is hereby authorized to charge such fee to our Deposit Account No. 18-0002 and notify us accordingly.

Date: October 9, 2007

Respectfully submitted,

Alun L. Palmer – Reg. No.: 47,838
RABIN & BERDO, PC
Correspondence Customer Number: 23995

FEE ENCLOSED: \$ 0.00
Please charge any further fee to
our Deposit Account No. 18-0002